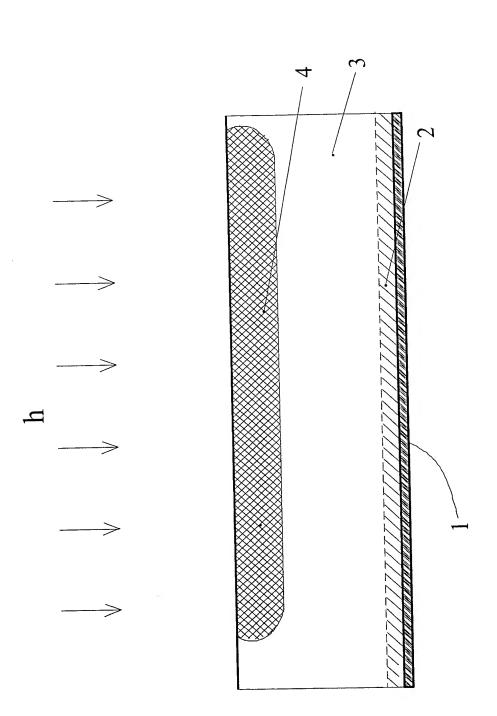
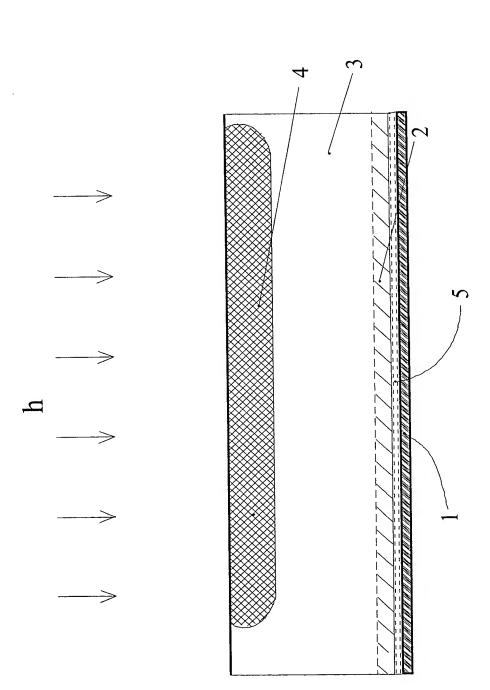
Blakely, Sokoloff, Taylor & Zafman LLP (714) 557-3800
Title: FAST SILICON PHOTODIODES WITH HIGH BACK SURFACE REFLECTANCE
IN A WAVELENGTH RANGE CLOSE TO THE BANDGAP
1st Named Inventor: Alexander O. Goushcha
Express Mail No.: EV323393842US Docket No.: 2712P010
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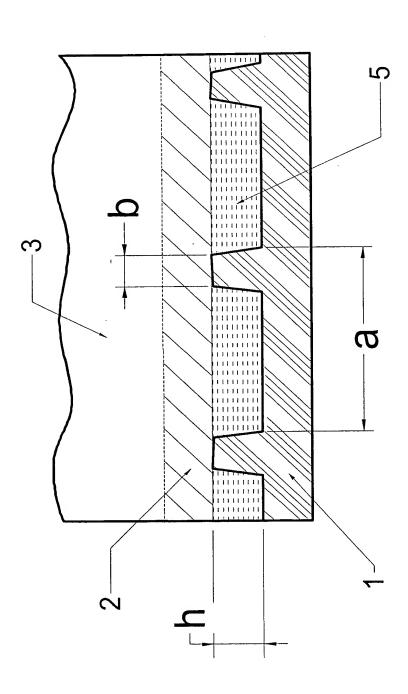
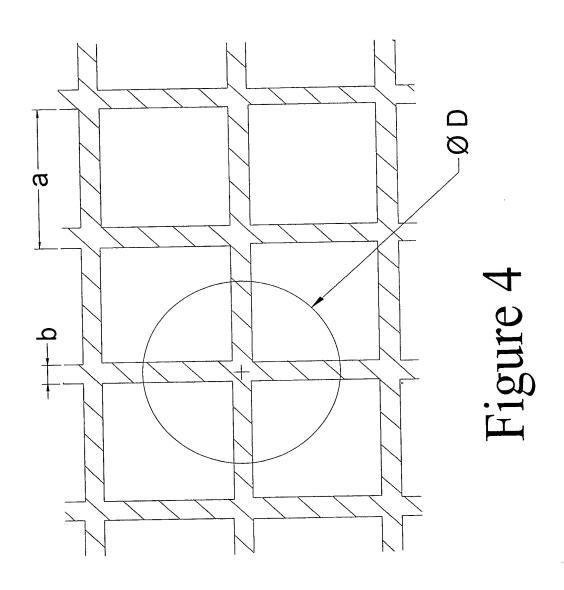


Figure 3

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